## NSN 5961-01-078-0357

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**Demilitarization:** 

No



View Online at https://aerobasegroup.com/nsn/5961-01-078-0357 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector to emitter, sustained and 60.0 collector to base voltage, dc and 7.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 15.00 amperes source cutoff current **Power Rating Per Characteristic:** 120.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin **Specification Data:** 80131-release6620 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:** 

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